

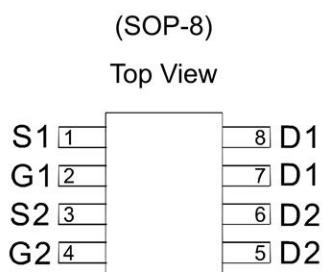
GENERAL FEATURES

- $R_{DS(ON)} \leq 16 \text{ m}\Omega @ V_{GS}=10\text{V}$
- $R_{DS(ON)} \leq 20 \text{ m}\Omega @ V_{GS}=4.5\text{V}$
- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability

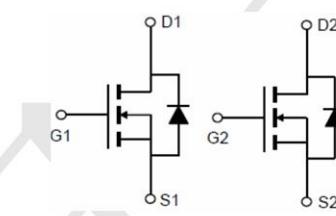
Application

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

Package and Pin Configuration

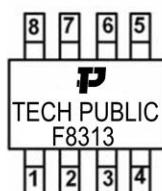


Circuit diagram



Schematic diagram

Marking:



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Maximum Ratings	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	10	A
		8.3	
Pulsed Drain Current	I_{DM}	38	A
Maximum Power Dissipation	P_D	2	W
		1.2	
Operating Junction Temperature	T_J	-55 to 150	$^\circ\text{C}$
Thermal Resistance-Junction to Ambient*	$R_{\theta JA}$	52.0	$^\circ\text{C/W}$



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Dual N-Channel Enhancement Mode Power MOSFET

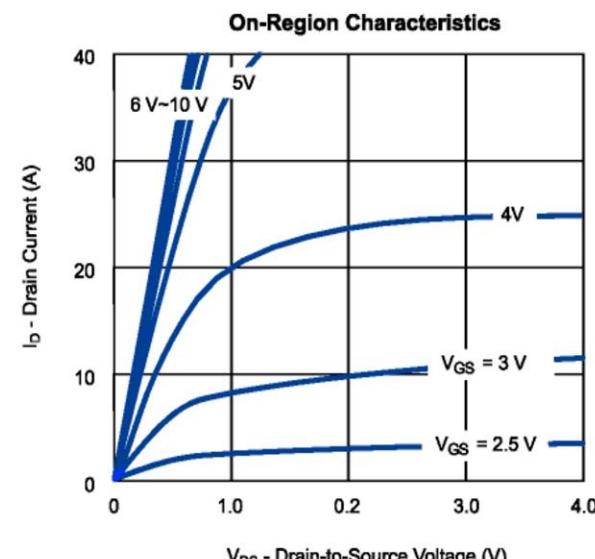
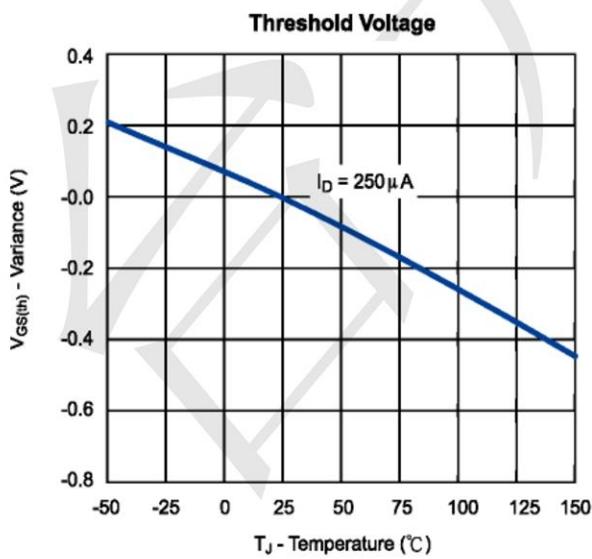
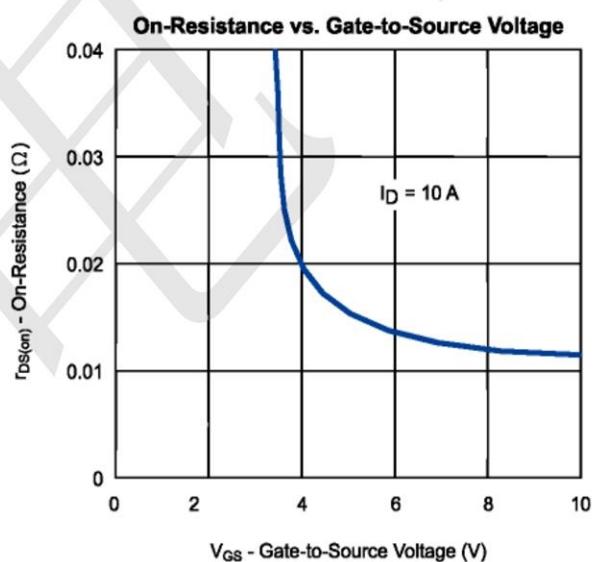
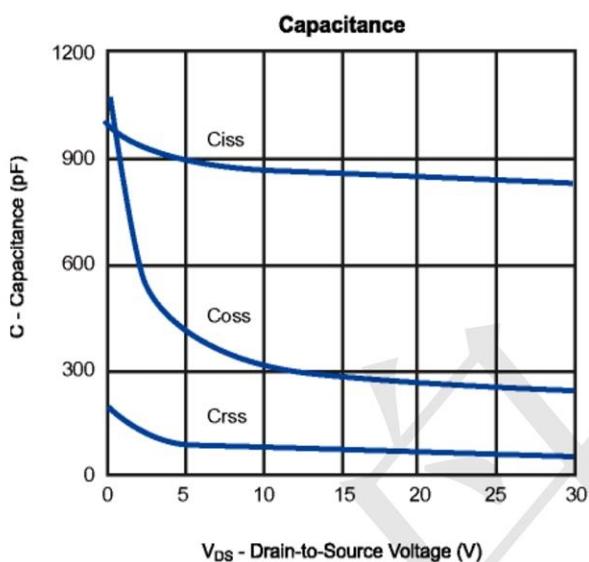
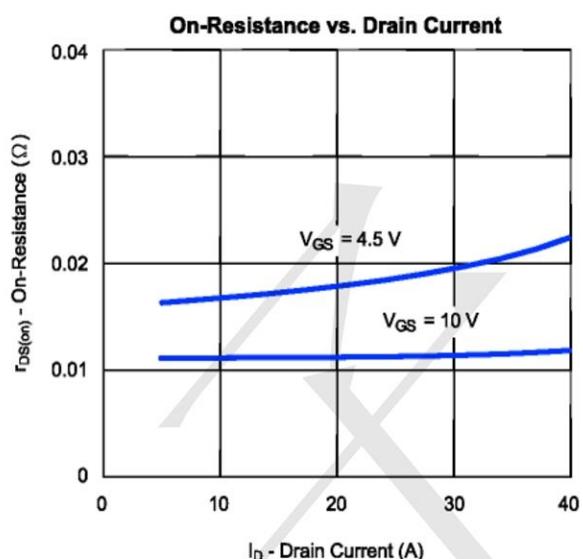
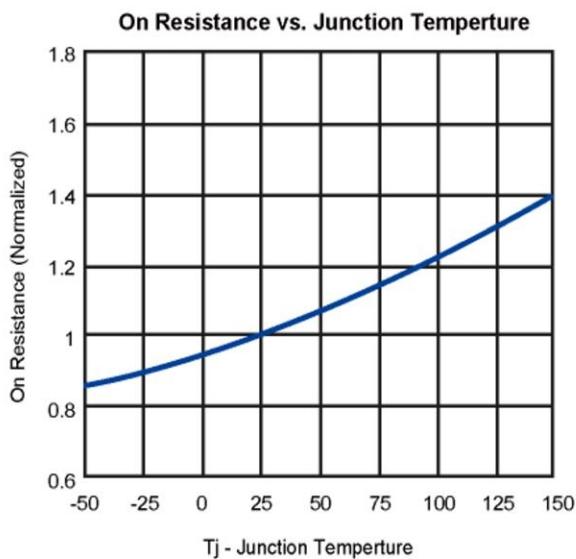
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Electrical Characteristics ($T_A = 25^\circ C$ Unless Otherwise Specified)

Symbol	Parameter	Limit	Min	Typ	Max	Unit
STATIC						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250 \mu A$	30			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250 \mu A$	1		3	V
I_{GSS}	Gate Leakage Current	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=24V, V_{GS}=0V$			1	μA
$R_{DS(on)}$	Drain-Source On-Resistance ^a	$V_{GS}=10V, I_D= 10A$		11.2	16	$m\Omega$
		$V_{GS}=4.5V, I_D= 8A$		15.6	20	
V_{SD}	Diode Forward Voltage	$I_S=8.2A, V_{GS}=0V$		0.8	1.2	V
DYNAMIC						
R_g	Gate Resistance	$f=1MHz$		1		Ω
Q_g	Total Gate Charge	$V_{DS}=10V, V_{GS}=4.5V, I_D=8.2A$		9.5		nC
Q_{gs}	Post-V _{th} Gate-Source Charge			3.6		
Q_{gd}	Gate-Drain Charge			3.4		
C_{iss}	Input Capacitance	$V_{DS}=25V, V_{GS}=0V, f=1MHz$		841		pF
C_{oss}	Output Capacitance			250		
C_{rss}	Reverse Transfer Capacitance			71		
$t_{d(on)}$	Turn-On Delay Time	$V_{DD}=15V, R_L = 15\Omega$ $I_D=1A, V_{GEN}=10V,$ $R_G=6\Omega$		14		ns
t_r	Turn-On Rise Time			12		
$t_{d(off)}$	Turn-Off Delay Time			43		
t_f	Turn-Off Fall Time			4		

Notes: a. pulse test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$, Guaranteed by design, not subject to production testing.

b. Matsuki Electric/ Force mos reserves the right to improve product design, functions and reliability without notice



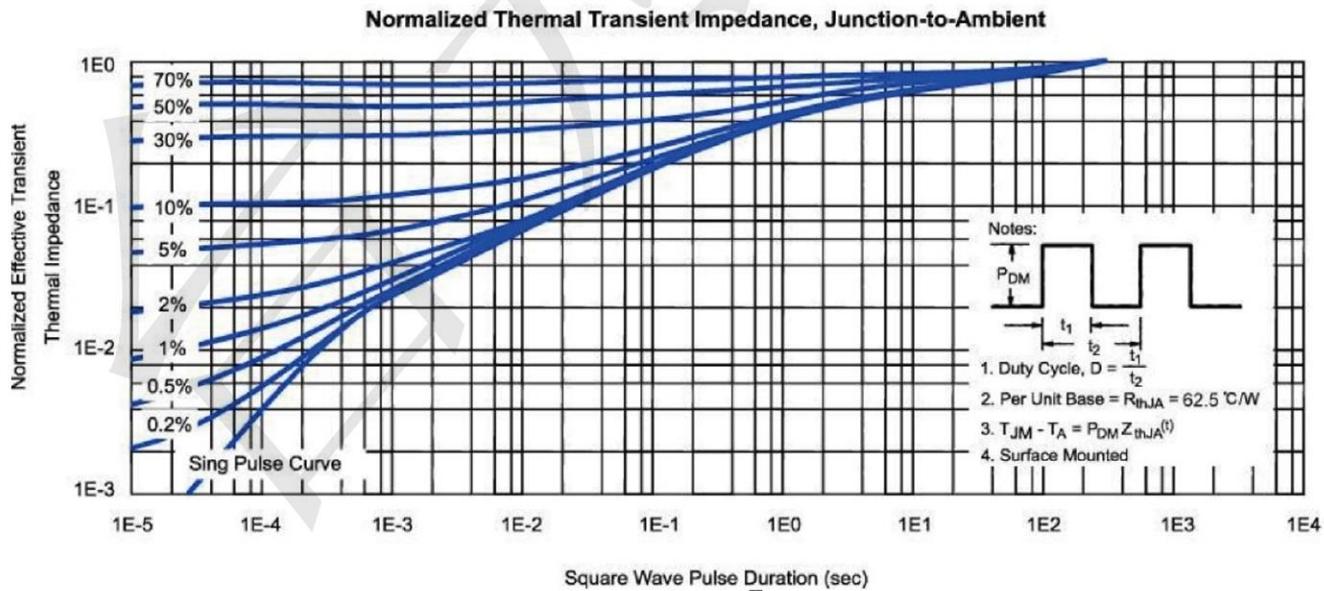
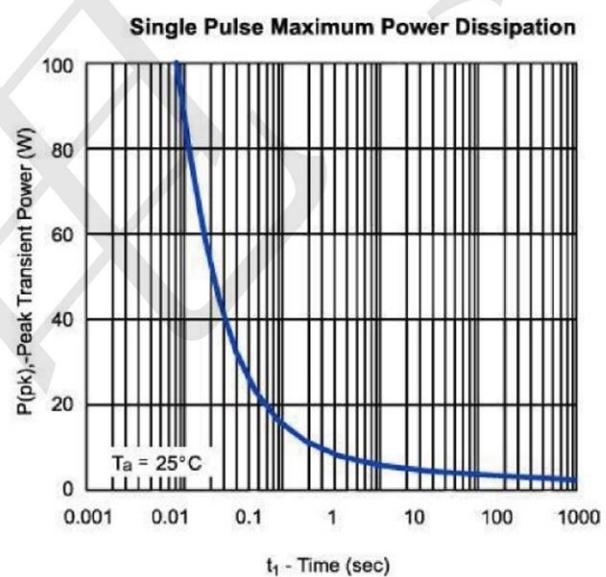
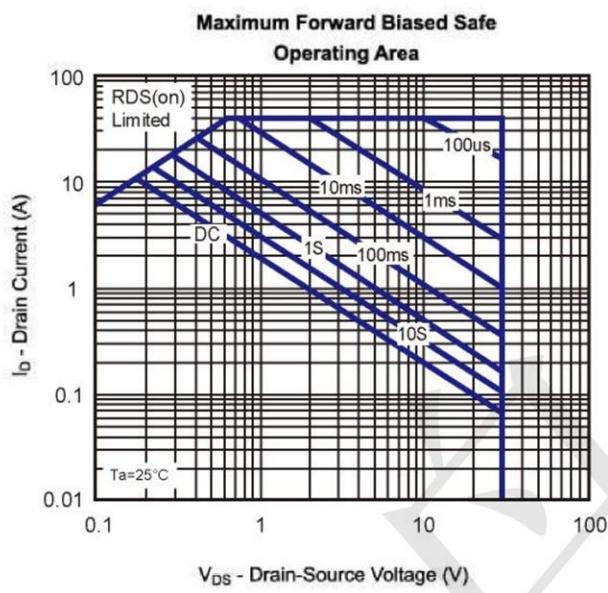
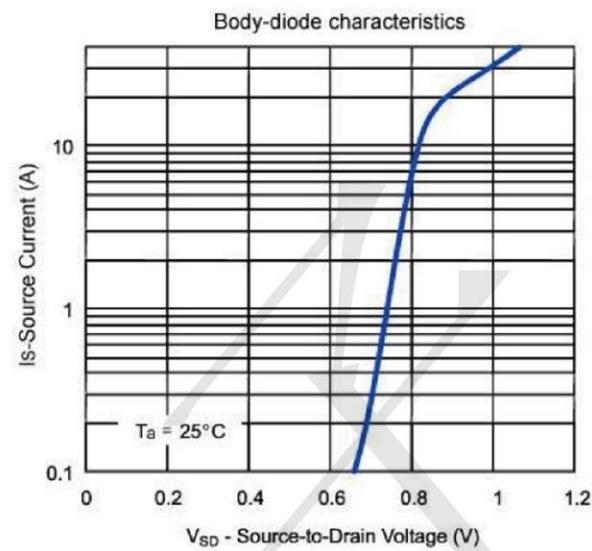
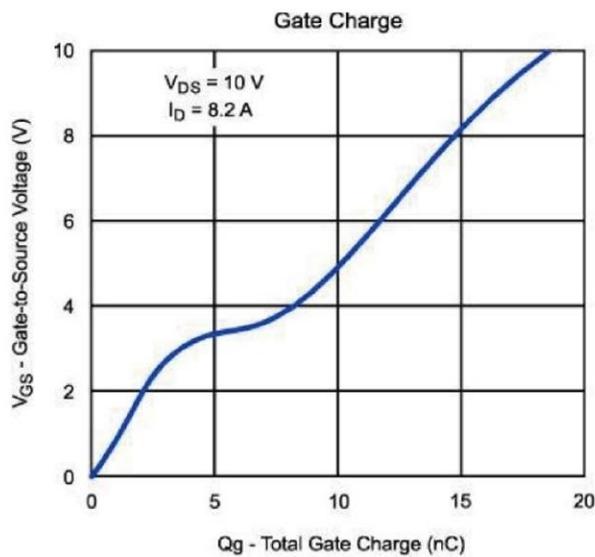


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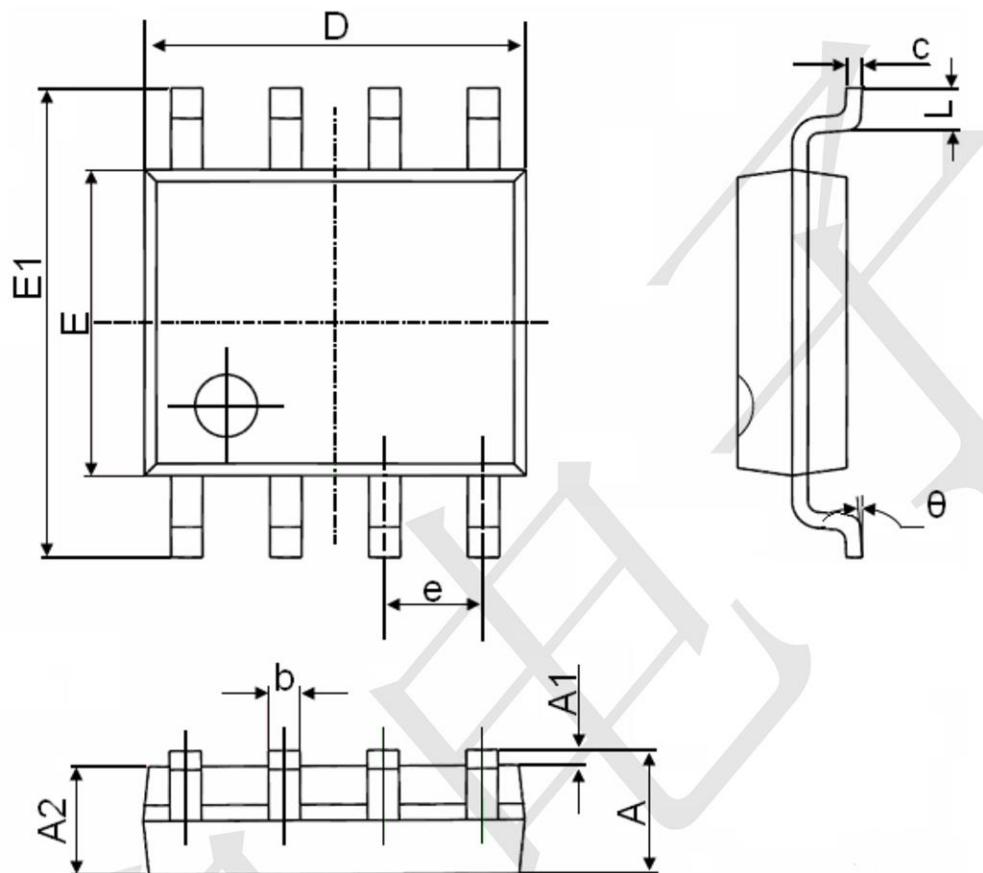
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SOP-8 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

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